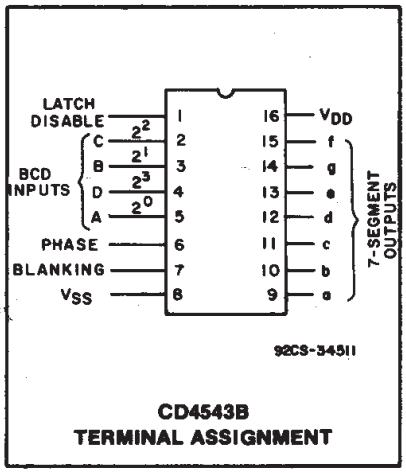
TEXAS INSTRUMENTS
Data sheet acquired from Harris Semiconductor
SCHS086

CD4543B Types

CMOS BCD-to-Seven-Segment Latch/Decoder/Driver For Liquid-Crystal Displays

High-Voltage Types (20-Volt Rating)



CD4543B
TERMINAL ASSIGNMENT

Features:
- *Display blanking of all illegal input combinations*
- *Latch storage of code*
- *Capability of driving two low power TTL loads, two HTL loads, or one low power Schottky load over the full rated-temperature range*
- *Pin-for-pin replacement for the CD4056B (with pin 7 tied to V_{SS})*
- *Direct LED driving capability*
- *100% tested for quiescent current at 20 V*
- *Maximum input current of 1 μA at 18 V over full package-temperature range; 100 nA at 18 V and 25°C*
- *Noise margin (full package-temperature range)= 1 V at V_{DD}=5 V; 2 V at V_{DD}=10 V; 2.5 V at V_{DD}=15 V*
- *5-V, 10-V, and 15-V parametric ratings*
- *Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"*

Applications:
- *Instrument display driver*
- *Dashboard display driver*
- *Computer/calculator display driver*
- *Timing device driver (clocks, watches, timers)*

■ CD4543B is a BCD-to-seven segment latch/decoder/driver designed primarily for liquid-crystal display (LCD) applications. It is also capable of driving light emitting diode (LED), incandescent, gas-discharge, and fluorescent displays. This device is functionally similar to and serves as direct replacement for the CD4056B when pin 7 is connected to V_{SS}. It differs from the CD4056B in that it has a display blanking capability instead of a level-shifting function and requires only one power supply. When the CD4056B is used in the level shifting mode, two power supplies are required. When the CD4543B is used for LCD applications, a square wave must be applied to the PHASE input and the backplane of the LCD device. For LED applications a logic 1 is required at the PHASE input for common-cathode devices; a logic 0 is required for common-anode devices (see truth table).

The CD4543B is supplied in hermetic dual-in-line ceramic packages (D and F suffixes), 16-lead dual-in-line plastic packages (E suffix), and in chip form (H suffix).

MAXIMUM RATINGS, *Absolute-Maximum Values:*

DC SUPPLY-VOLTAGE RANGE, (V_{DD})
Voltages referenced to V_{SS} Terminal) ..... -0.5V to +20V
INPUT VOLTAGE RANGE, ALL INPUTS ..... -0.5V to V_{DD} +0.5V
DC INPUT CURRENT, ANY ONE INPUT ..... ±10mA
POWER DISSIPATION PER PACKAGE (P_D):
For T_A = -55°C to +100°C 500mW
For T_A = +100°C to +125°C ..... Derate Linearity at 12mW/°C to 200mW
DEVICE DISSIPATION PER OUTPUT TRANSISTOR
FOR T_A = FULL PACKAGE-TEMPERATURE RANGE (All Package Types) 100mW
OPERATING-TEMPERATURE RANGE (T_A) ..... -55°C to +125°C
STORAGE TEMPERATURE RANGE (T_{stg}) ..... -65°C to +150°C
LEAD TEMPERATURE (DURING SOLDERING):
At distance 1/16 ± 1/32 inch (1.59 ± 0.79mm) from case for 10s max ..... +265°C

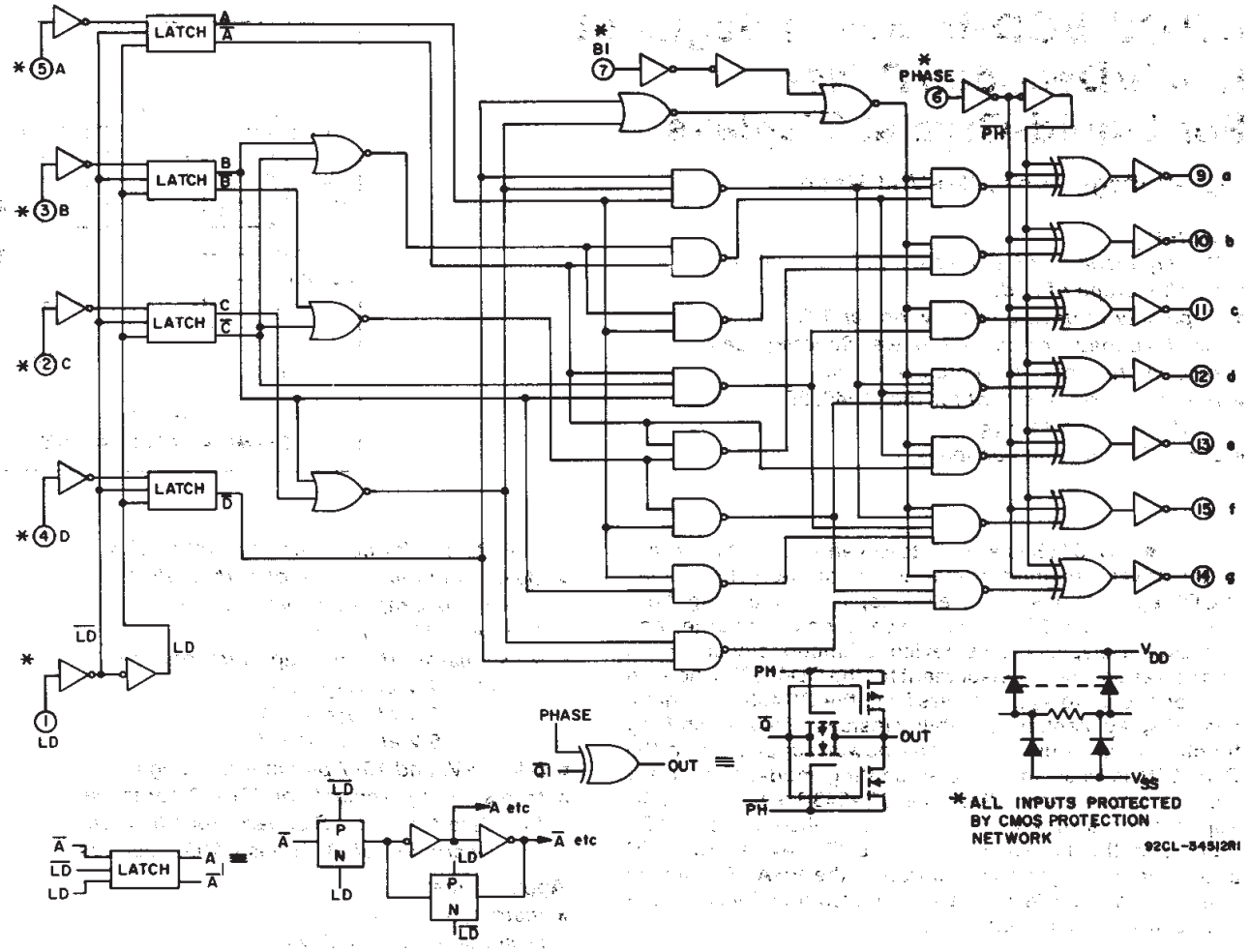


Fig. 1 - BCD-to-seven-segment latch/decoder/driver CD4543B logic circuit diagram.

RECOMMENDED OPERATING CONDITIONS at T_A=25°C, Unless Otherwise Specified
For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC		V_{DD} (V)	LIMITS		UNITS
			MIN.	TYP.	
Supply-Voltage Range (For T_A=Full Package-Temperature Range)		—	3	18	V
Latch Disable Pulse Width	t_{WH}	5	250	125	ns
		10	100	50	
		15	80	40	
Minimum Data Setup Time	t_{SU}	5	60	15	
		10	20	-5	
		15	10	-5	
Minimum Data Hold Time	t_H	5	25	-5	
		10	20	10	
		15	20	10	

STATIC ELECTRICAL CHARACTERISTICS

CHARACTERISTIC		CONDITIONS			LIMITS AT INDICATED TEMPERATURES (°C)							UNITS
		V_O (V)	V_{IN} (V)	V_{DD} (V)	-55	-40	+85	+125	+25 Min.	+25 Typ.	+25 Max.	
Quiescent Device Current Max.	I_{DD}	—	0, 5	5	5	5	150	150	—	0.04	5	μA
		—	0,10	10	10	10	300	300	—	0.04	10	
		—	0,15	15	20	20	600	600	—	0.04	20	
		—	0,20	20	100	100	3000	3000	—	0.08	100	
Output Low (Sink) Current Min.	I_{OL}	0.4	0, 5	5	0.64	0.61	0.42	0.36	0.51	1	—	mA
		0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6	—	
		1.5	0,15	15	4.2	4	2.8	2.4	3.4	6.8	—	
Output High (Source) Current Min.	I_{OH}	4.6	0, 5	5	-0.46	-0.44	-0.30	-0.26	-0.37	-0.75	—	
		2.5	0, 5	5	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	—	
		9.5	0,10	10	-0.98	-0.92	-0.68	-0.55	-0.8	-1.6	—	
		13.5	0,15	15	-3.33	-3.18	-2.2	-1.9	-2.7	-5.4	—	
Output Voltage: Low-Level Max.	V_{OL}	—	0, 5	5	0.05				—	0	0.05	V
		—	0,10	10	0.05				—	0	0.05	
		—	0,15	15	0.05				—	0	0.05	
Output Voltage: High-Level Min.	V_{OH}	—	0, 5	5	4.95				4.95	5	—	
		—	0,10	10	9.95				9.95	10	—	
		—	0,15	15	14.95				14.95	15	—	
Input Low Voltage Max.	V_{IL}	0.5,4.5	—	5	1.5				—	—	1.5	V
		1, 9	—	10	3				—	—	3	
		1.5,13.5	—	15	4				—	—	4	
Input High Voltage Min.	V_{IH}	0.5,4.5	—	5	3.5				3.5	—	—	
		1, 9	—	10	7				7	—	—	
		1.5,13.5	—	15	11				11	—	—	
Input Current Max.	I_{IN}	—	0,18	18	±0.1	±0.1	±1	±1	—	$±10^{-5}$	±0.1	μA

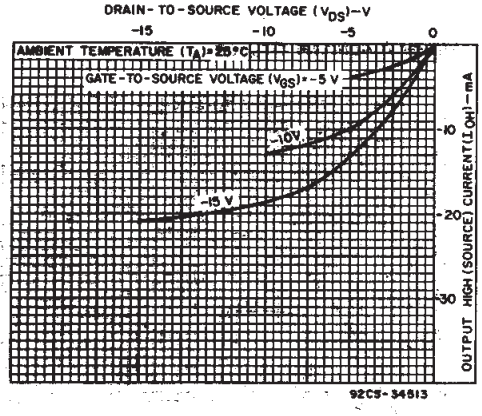


Fig. 2 – Typical output high (source) current characteristics.

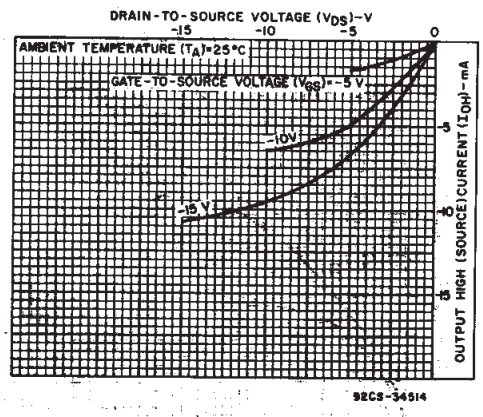


Fig. 3 – Minimum output high (source) current characteristics.

DYNAMIC ELECTRICAL CHARACTERISTICS at T_A=25° C; C_L=50 pF, Input t_r,t_f=20 ns, R_L=200 kΩ

CHARACTERISTIC		TEST CONDITIONS V_{DD} (V)	LIMITS All Packages MIN.	TYP.	MAX.	UNITS
Propagation Delay Time	t_{PHL}	5	—	600	1200	ns
		10	—	200	400	
		15	—	150	300	
	t_{PLH}	5	—	500	1000	
		10	—	200	400	
		15	—	150	300	
Transition Time	t_{THL}	5	—	180	360	
		10	—	90	180	
		15	—	65	130	
	t_{TLH}	5	—	180	360	
		10	—	90	180	
		15	—	65	130	
Latch Disable Pulse Width	t_{WH}	5	250	125	—	
		10	100	50	—	
		15	80	40	—	
Address Setup Time	t_{SU}	5	60	15	—	
		10	20	-5	—	
		15	10	-5	—	
Address Hold Time	t_H	5	25	-5	—	
		10	20	10	—	
		15	20	10	—	
Input Capacitance	C_{IN}	Any Input	—	5	7.5	pF

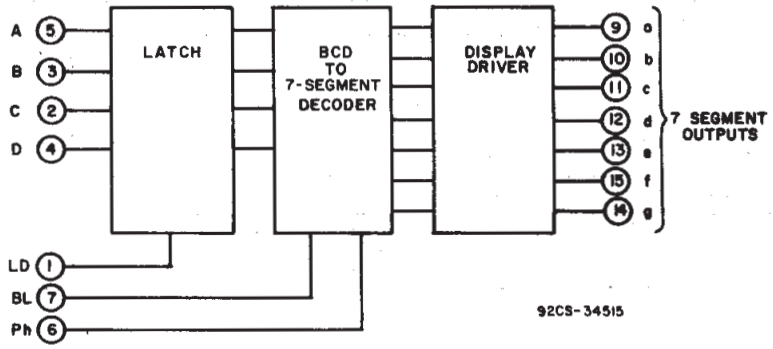


Fig. 4 - BCD-to-seven-segment latch/decoder/driver functional diagram.

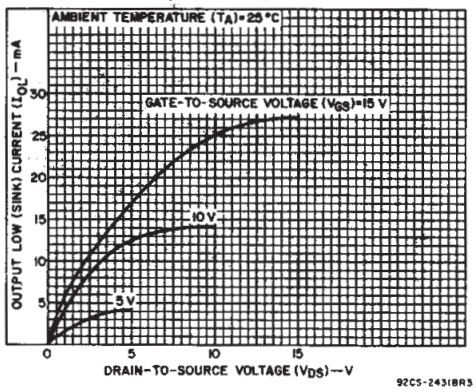


Fig. 5 - Typical output low (sink) current characteristics.

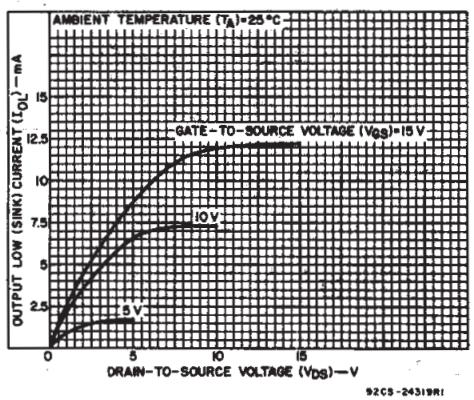


Fig. 6 - Minimum output low (sink) current characteristics.

TRUTH TABLE FOR CD4543B

INPUT CODE							OUTPUT STATE							DISPLAY CHARACTER
LD	BI	Ph*	D	C	B	A	a	b	c	d	e	f	g	
X	1	0	X	X	X	X	0	0	0	0	0	0	0	
1	0	0	0	0	0	0	1	1	1	1	1	1	0	0
1	0	0	0	0	0	1	0	1	1	0	0	0	0	1
1	0	0	0	0	1	0	1	1	0	1	1	0	1	2
1	0	0	0	0	1	1	1	1	1	1	0	0	1	3
1	0	0	0	1	0	0	0	1	1	0	0	1	1	4
1	0	0	0	1	0	1	1	0	1	1	0	1	1	5
1	0	0	0	1	1	0	1	0	1	1	1	1	1	6
1	0	0	0	1	1	1	1	1	1	0	0	0	0	7
1	0	0	1	0	0	0	1	1	1	1	1	1	1	8
1	0	0	1	0	0	1	1	1	1	1	0	1	1	9
1	0	0	1	0	1	0	0	0	0	0	0	0	0	Blank
1	0	0	1	0	1	1	0	0	0	0	0	0	0	Blank
1	0	0	1	1	0	0	0	0	0	0	0	0	0	Blank
1	0	0	1	1	0	1	0	0	0	0	0	0	0	Blank
1	0	0	1	1	1	0	0	0	0	0	0	0	0	Blank
1	0	0	1	1	1	1	0	0	0	0	0	0	0	Blank
0	0	0	X	X	X	X	**							**
†	†	1	†				Inverse of Output Combinations Above							Display as above

X=Don't care.

†=Above combinations.

*=For liquid-crystal readouts, apply a square wave to Ph.
For common cathode LED readouts, select Ph=0.
For common anode LED readouts, select Ph=1.

**=Depends upon the BCD code previously applied when LD=1.

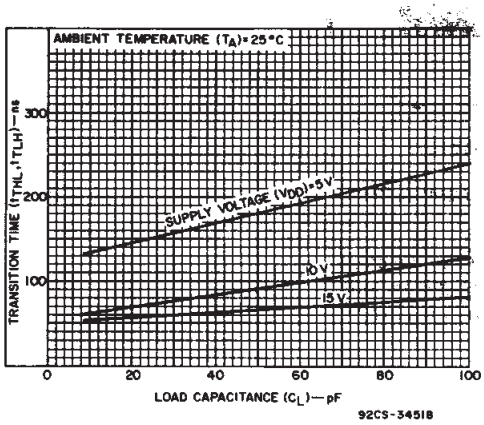


Fig. 7 - Typical transition time as a function of load capacitance.

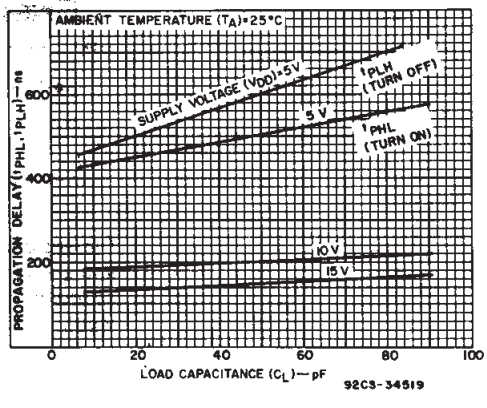


Fig. 8 - Typical propagation delay time as a function of load capacitance.

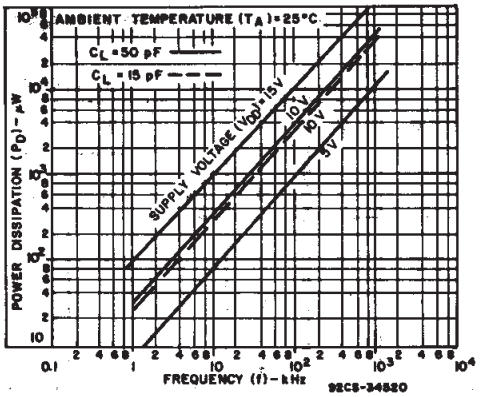


Fig. 9 – Typical dynamic power dissipation as a function of frequency.

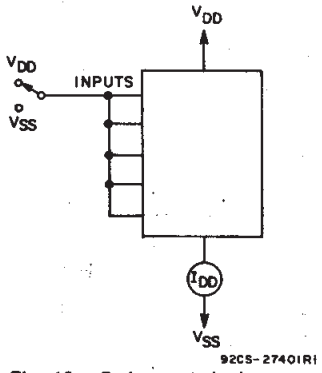


Fig. 10 – Quiescent device current test circuit.

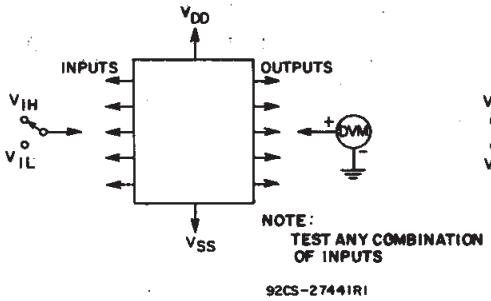


Fig. 11 – Input voltage test circuit.

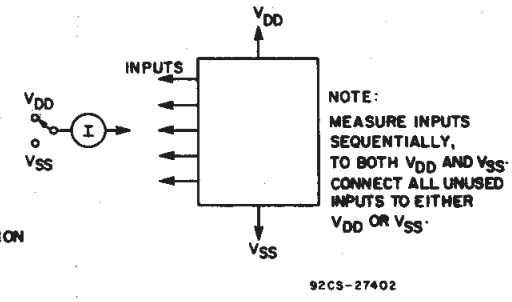
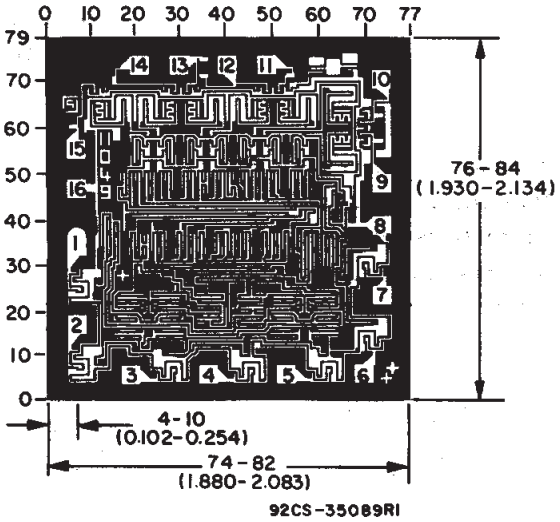


Fig. 12 – Input current test circuit.



Dimensions and pad layout for CD4543BH.

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).

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